MSB1218A-RT1G

PNP Silicon General Purpose Amplifier Transistor

This PNP Silicon Epitaxial Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- High h_{FE}, 210 460
- Low $V_{CE(sat)}$, < 0.5 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

| Rating | Symbol | Value | Unit |
|--------------------------------|----------------------|-------|------|
| Collector-Base Voltage | V _{(BR)CBO} | 45 | Vdc |
| Collector-Emitter Voltage | $V_{(BR)CEO}$ | 45 | Vdc |
| Emitter-Base Voltage | $V_{(BR)EBO}$ | 7.0 | Vdc |
| Collector Current - Continuous | I _C | 100 | mAdc |
| Collector Current - Peak | $I_{C(P)}$ | 200 | mAdc |

THERMAL CHARACTERISTICS

| Rating | Symbol | Max | Unit |
|----------------------------|------------------|-------------|------|
| Power Dissipation (Note 1) | P _D | 150 | mW |
| Junction Temperature | TJ | 150 | °C |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | Min | Max | Unit |
|---|----------------------|-----|-----|------|
| Collector-Emitter Breakdown Voltage ($I_C = 2.0 \text{ mAdc}, I_B = 0$) | V _{(BR)CEO} | 45 | - | Vdc |
| Collector-Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$) | V _{(BR)CBO} | 45 | - | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = 10 \mu Adc, I_E = 0$) | V _{(BR)EBO} | 7.0 | - | Vdc |
| Collector-Base Cutoff Current (V _{CB} = 20 Vdc, I _E = 0) | I _{CBO} | - | 0.1 | μΑ |
| Collector-Emitter Cutoff Current $(V_{CE} = 10 \text{ Vdc}, I_B = 0)$ | I _{CEO} | - | 100 | μΑ |
| DC Current Gain (Note 2) (V _{CE} = 10 Vdc, I _C = 2.0 mAdc) | h _{FE1} | 210 | 340 | - |
| Collector-Emitter Saturation Voltage (Note 2) (I _C = 100 mAdc, I _B = 10 mAdc) | V _{CE(sat)} | - | 0.5 | Vdc |

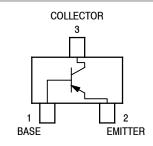
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.
- 2. Pulse Test: Pulse Width ≤ 300 µs, D.C. ≤ 2%.



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SC-70 (SOT-323) CASE 419 STYLE 4

MARKING DIAGRAM



BR = Device Code
M = Date Code*
• Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending
upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|--------------------|-----------------------|
| MSB1218A-RT1G | SC-70 (Pb-Free) | 3000 /Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSB1218A-RT1G

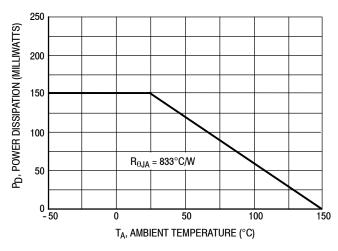
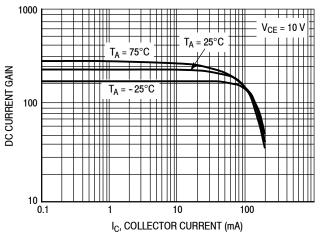


Figure 1. Derating Curve

Figure 2. I_C - V_{CE}



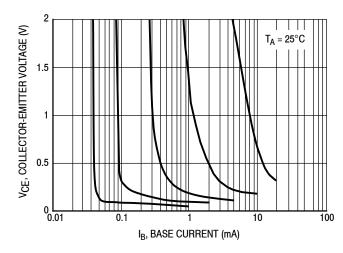
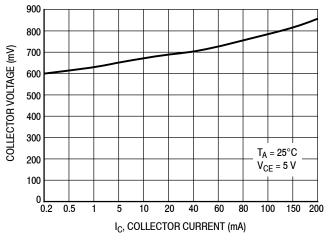


Figure 3. DC Current Gain

Figure 4. Collector Saturation Region



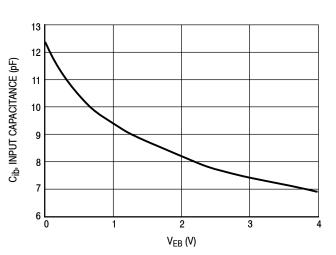


Figure 5. On Voltage

Figure 6. Capacitance

MSB1218A-RT1G

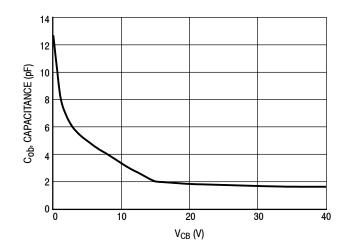


Figure 7. Capacitance





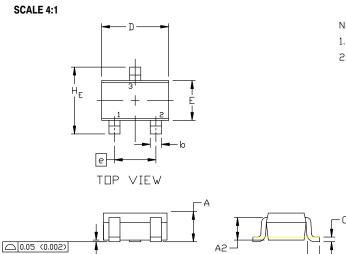
SC-70 (SOT-323) **CASE 419** ISSUE R

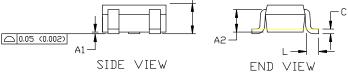
DATE 11 OCT 2022

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

| | MILLIMETERS | | | | TNICHES | | |
|-----|-------------|----------|------|-------|-----------|-------|--|
| | MILLIMETERS | | | | INCHES | | |
| DIM | MIN. | N□M. | MAX. | MIN. | N□M. | MAX. | |
| Α | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 | |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 | |
| A2 | | 0.70 REF | | | 0.028 BSC | | |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 | |
| С | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 | |
| D | 1.80 | 2.00 | 2.20 | 0.071 | 0.080 | 0.087 | |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 | |
| е | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 | |
| e1 | 0.65 BSC | | | | 0.026 BS | C | |
| L | 0.20 | 0.38 | 0.56 | 0.008 | 0.015 | 0.022 | |
| HE | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 | |





GENERIC MARKING DIAGRAM



= Specific Device Code XX

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

| 0.65 [0.025] |
|--------------|
| |
| 1.90 [0.075] |
| 0.90 [0.035] |
| 0.70 [0.028] |

For additional information on our Pb-Free strategy and soldering details, please download the IN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

| STYLE 1: CANCELLED | STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE | STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE | |
|-----------------------------|---|---|--|--|---------------------------|
| STYLE 6: | STYLE 7: | STYLE 8: | STYLE 9: | STYLE 10: | STYLE 11: |
| PIN 1. EMITTER | PIN 1. BASE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. CATHODE |
| 2. BASE | 2. EMITTER | 2. SOURCE | 2. CATHODE | 2. ANODE | CATHODE |
| COLLECTOR | COLLECTOR | 3. DRAIN | CATHODE-ANODE | 3. ANODE-CATHODE | CATHODE |

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|------------------|-----------------|--|-------------|--|
| DESCRIPTION: | SC-70 (SOT-323) | | PAGE 1 OF 1 | |

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